

Notice: Some parametric limits are subject to change.

TYPE  
NAME

**ML920J45S , ML920K45S, ML920Y45S**  
**ML925B45F , ML925C45F**

## DESCRIPTION

ML9XX45 series are InGaAsP laser diodes which provide a stable, single transverse mode oscillation with emission wavelength of 1550nm and standard continuous light output of 5mW.

ML9XX45 are hermetically sealed devices having the photo diode for optical output monitoring. This is suitable for such applications as FTTH (Fiber to the Home)systems.

## FEATURES

- 1550 or 1520nm typical emission wavelength, FP-LDs
- Low threshold current, low operating current
- Wide temperature range operation ( $T_c = -40$  to  $85\text{deg.C}$ )
- $\phi 5.6\text{mm}$  TO-CA N package  
Flat window cap : ML920J45S, ML925B45F  
Ball lens cap : ML920K45S, ML925C45F, ML920Y45S

## APPLICATION

- ~155Mbps FTTH system

## ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter             | Conditions | Ratings     | Unit  |
|--------|-----------------------|------------|-------------|-------|
| Po     | Light output power    | CW         | 6[4]        | mW    |
| VRL    | Laser reverse voltage | -          | 2           | V     |
| VRD    | PD reverse voltage    | -          | 20          | V     |
| IFD    | PD forward current    | -          | 2           | mA    |
| Tc     | Operation temperature | -          | -40 to +85  | deg.C |
| Tstg   | Storage temperature   | -          | -40 to +100 | deg.C |

ELECTRICAL/OPTICAL CHARACTERISTICS( $T_c=25^\circ\text{C}$ )

| Symbol             | Parameter  | Test Conditions              | Min.                               | Typ.                 | Max. | Unit          |
|--------------------|--|------------------------------|------------------------------------|----------------------|------|---------------|
| Ith                | Threshold current                                  | CW                           | 3                                  | 10                   | 20   | mA            |
| Iop                | Operation current                                  | CW, Po=5mW[3mW]              | 10                                 | 30                   | 50   | mA            |
| Vop                | Operating voltage                                  | CW, Po=5mW[3mW]              | ---                                | 1.1                  | 1.5  | V             |
| $\eta$             | Slope efficiency                                   | CW, Po=5mW[3mW]              | 0.15[0.1]                          | 0.25[0.2]            | 0.5  | mW/mA         |
| $\lambda_c$        | Center wavelength                                  | CW, Po=5mW[3mW]              | 1520<br>-01spec<br>1495<br>-02spec | 1550<br>1520<br>1544 | 1580 | nm            |
| $\Delta\lambda$    | Spectral Width                                     | CW, Po=5mW, [3mW]RMS(-20dB)  | ---                                | 1.5                  | 3    | nm            |
| $\theta \parallel$ | Beam divergence angle(parallel)                    | CW, Po=5mW[3mW]              | ---                                | 25[11]               | ---  | deg.          |
| $\theta \perp$     | Beam divergence angle (perpendicular)              | CW, Po=5mW[3mW]              | ---                                | 30[11]               | ---  | deg.          |
| tr,tf              | Rise and Fall time (10%-90%)                       | Ib=Ith, Po=5mW [3mW], 10-90% | ---                                | 0.3                  | 0.7  | nsec          |
| Im                 | Monitor Current (PD)                               | CW, Po=5mW[3mW], VRD=1V,     | 0.1                                | 0.5                  | 1.0  | mA            |
| Id                 | Dark Current (PD)                                  | VRD=10V                      | ---                                | ---                  | 0.1  | $\mu\text{A}$ |
| Ct                 | Capacitance (PD)                                   | VRD=10V, f=1MHz              | ---                                | 10                   | 20   | pF            |
| Pf(Note2)          |  | CW, PL=3mW, SI10/125         | 0.2                                | 0.5                  | ---  | mW            |
| Df(Note2)          | Fiber Coupling characteristics at peak coupling<3> | CW, PL=3mW<br>SI10/125       | 5.0                                | 5.8                  | 6.2  | mm            |
|                    |  | ML920K45S<br>ML925C45F       | 6.0                                | 6.5                  | 7.0  |               |
|                    |  | ML920Y45S                    |                                    |                      |      |               |

Note : &lt;1&gt; [ ] applied to the lens cap type.

Note : &lt;2&gt; Pf,Df are applied to the ball lens type.

Note : &lt;3&gt; Df is a distance between reference plane of the base to the fiber.

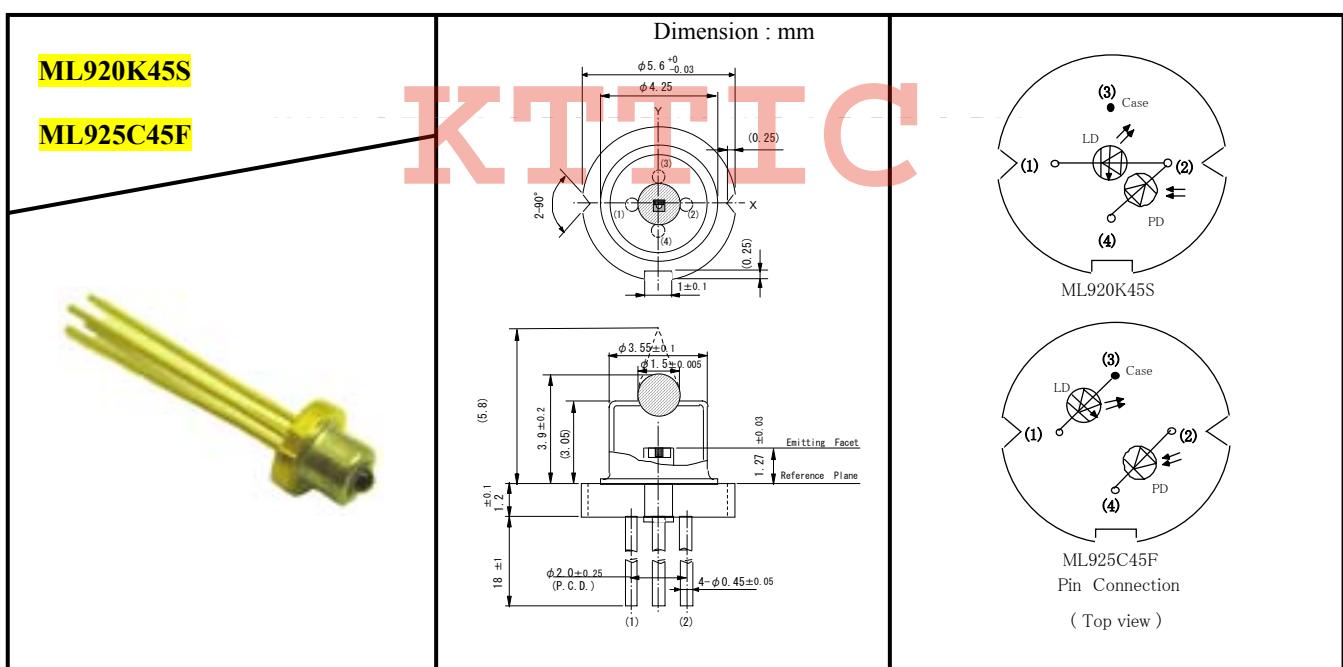
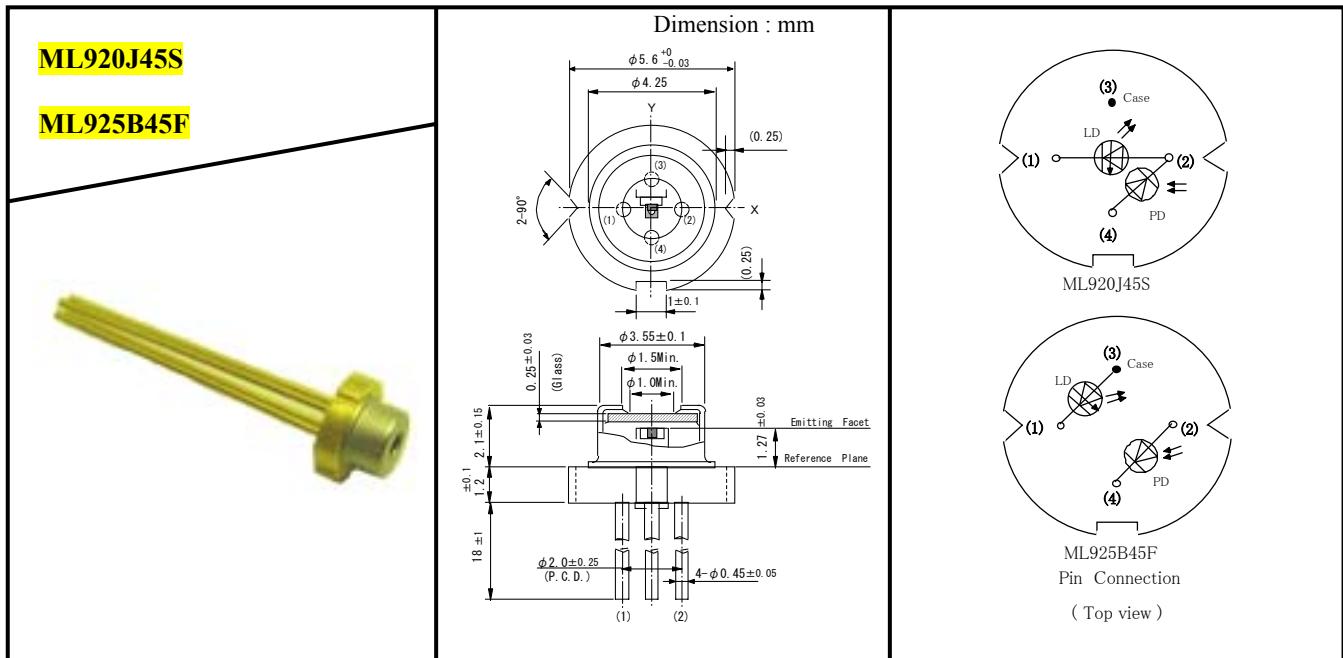
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# ML9xx45 SERIES

1550,1520nm InGaAsP FP LASER DIODES

## OUTLINE DRAWINGS



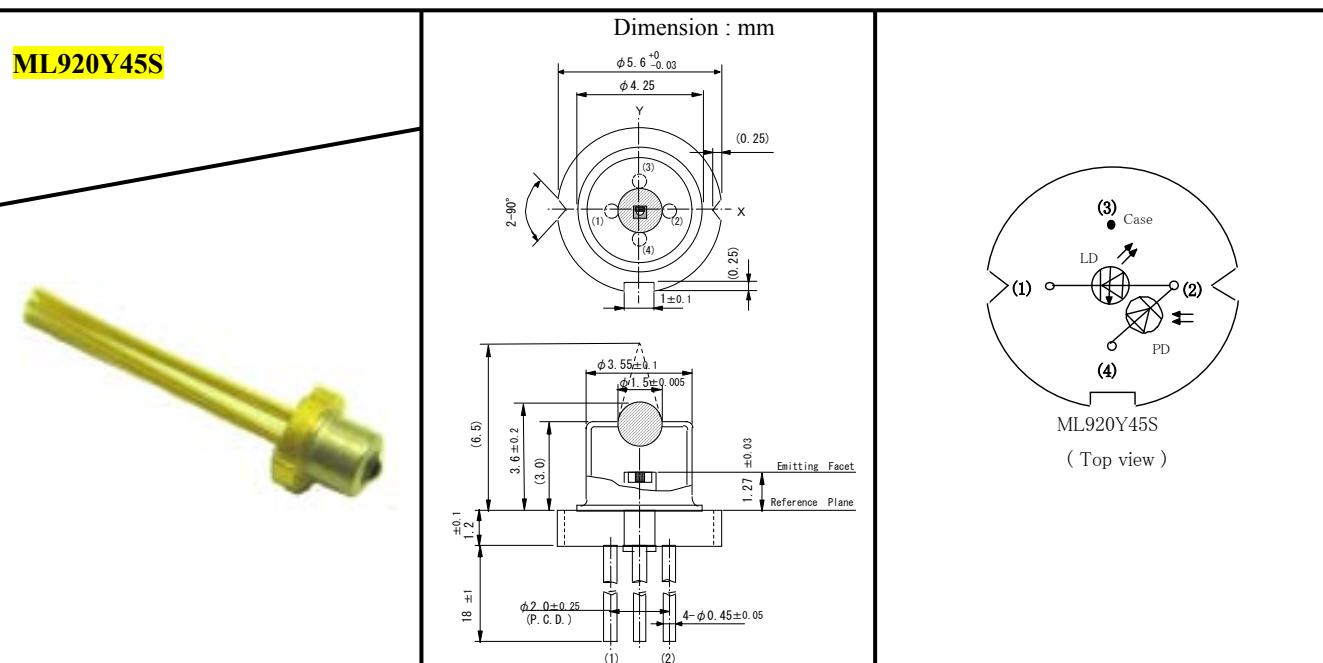
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